

1ch Small Package High Side Switch ICs

0.75A Current Limit Latch Off High Side Switch ICs

BD2220G BD2221G

General Description

BD2220G and BD2221G are low ON-Resistance N-Channel MOSFET high-side power switches, optimized for Universal Serial Bus (USB) applications. BD2220G and BD2221G are equipped with the function of over-current detection, thermal shutdown, under-voltage lockout and soft-start.

Features

- Low ON-Resistance (Typ 160mΩ) N-Channel MOSFET Built-in
- Over-Current Detection (Output OFF-Latch Operation)
- Thermal Shutdown
- Open-Drain Fault Flag Output
- Flag Output Delay
- Under-Voltage Lockout
- Soft-Start Circuit
- Control Input Logic

Active-High: BD2220G
Active-Low: BD2221G

■ Reverse Current Protection when Power Switch Off

Applications

USB hub in consumer appliances, PC, PC peripheral equipment, and so forth

Key Specifications

Input Voltage Range: 2.7V to 5.5V

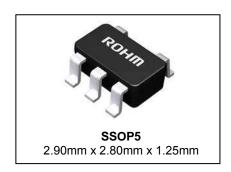
ON-Resistance: 160mΩ(Typ)

Over-Current Threshold: 0.5A (Min), 1.0A (Max)

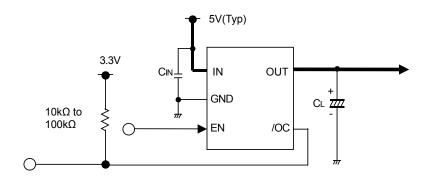
Standby Current: 0.01μA (Typ)

■ Operating Temperature Range: -40°C to +85°C

Package W(Typ) D (Typ) H (Max)



Typical Application Circuit

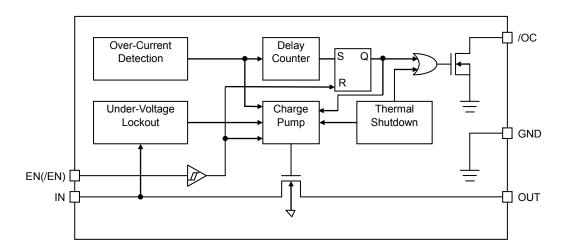


Lineup

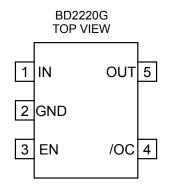
| Ove | r-Current Thres | hold | Control Input | ontrol Input Package Orderab | | Orderable Part Number |
|------|-----------------|------|---------------|------------------------------|--------------|-----------------------|
| Min | Тур | Max | Logic | F | ackage | Orderable Part Number |
| 0.5A | - | 1.0A | High | SSOP5 | Reel of 3000 | BD2220G-TR |
| 0.5A | - | 1.0A | Low | SSOP5 | Reel of 3000 | BD2221G-TR |

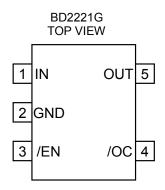
OProduct structure: Silicon monolithic integrated circuit OThis product has not designed protection against radioactive rays

Block Diagram



Pin Configurations





Pin Description

| Pin No. | Symbol | I/O | Function |
|---------|---------|-----|---|
| 1 | IN | - | Switch input and the supply voltage for the IC. |
| 2 | GND | - | Ground |
| 3 | EN, /EN | I | Enable input. EN: High level input turns on the switch. (BD2220G) /EN: Low level input turns on the switch. (BD2221G) |
| 4 | /OC | 0 | Over-current notification terminal. Low level output during over-current or over-temperature condition. Open-drain fault flag output. |
| 5 | OUT | 0 | Switch output |

Absolute Maximum Ratings (Ta=25°C)

| Parameter | Symbol | Rating | Unit |
|-----------------------|-------------------|--------------------------|------|
| IN Supply Voltage | V _{IN} | -0.3 to +6.0 | V |
| EN(/EN) Input Voltage | $V_{EN}, V_{/EN}$ | -0.3 to +6.0 | V |
| /OC Voltage | V _{/OC} | -0.3 to +6.0 | V |
| /OC Sink Current | I _{/OC} | 5 | mA |
| OUT Voltage | V _{OUT} | -0.3 to +6.0 | V |
| Storage Temperature | Tstg | -55 to +150 | °C |
| Power Dissipation | Pd | 0.67 ^(Note 1) | W |

(Note 1) Mounted on 70mm x 70mm x 1.6mm glass epoxy board. Reduce 5.4mW per 1°C above 25°C.

Caution: Operating the IC over the absolute maximum ratings may damage the IC. The damage can either be a short circuit between pins or an open circuit between pins and the internal circuitry. Therefore, it is important to consider circuit protection measures, such as adding a fuse, in case the IC is operated every the absolute maximum ratings. over the absolute maximum ratings.

Recommended Operating Conditions

| Darameter | Cymbol | | Rating | | |
|-----------------------|-----------------|-----|--------|-----|------|
| Parameter | Symbol | Min | Тур | Max | Unit |
| IN Operating Voltage | V _{IN} | 2.7 | 5.0 | 5.5 | V |
| Operating Temperature | Topr | -40 | - | +85 | °C |

Electrical Characteristics

BD2220G (V_{IN}= 5V, Ta= 25°C, unless otherwise specified.)

| DC Characteristics | | | | | 1 | |
|------------------------------|------------------|------|-------|------|-------|---|
| Parameter | Symbol | | Limit | | Unit | Conditions |
| Farameter | Symbol | Min | Тур | Max | Offic | Conditions |
| Operating Current | I _{DD} | - | 110 | 160 | μA | V _{EN} = 5V V _{OUT} = Open |
| Standby Current | I _{STB} | - | 0.01 | 5 | μΑ | $V_{EN} = 0V$ $V_{OUT} = Open$ |
| EN Input Voltage | V_{ENH} | 2.0 | - | - | V | High Input |
| EN Input Voltage | V_{ENL} | - | - | 8.0 | V | Low Input |
| EN Input Leakage | I _{EN} | -1.0 | +0.01 | +1.0 | μA | V _{EN} = 0V or 5V |
| ON-Resistance | R _{ON} | - | 160 | 210 | mΩ | I _{OUT} = 50mA |
| Switch Leak Current | I _{LSW} | - | - | 1.0 | μA | V _{EN} = 0V, V _{OUT} = 0V |
| Reverse Leak Current | I _{REV} | - | - | 1.0 | μA | V _{OUT} = 5.5V, V _{IN} = 0V |
| Over-Current Threshold | I _{TH} | 0.5 | - | 1.0 | Α | |
| Short Circuit Output Current | I _{SC} | 0.35 | - | - | Α | V _{OUT} = 0V, RMS |
| /OC Output Low Voltage | V _{/OC} | - | - | 0.4 | V | I _{/OC} = 0.5mA |
| IN A O The control of | V_{TUVH} | 2.1 | 2.3 | 2.5 | V | V _{IN} Increasing |
| UVLO Threshold | V_{TUVL} | 2.0 | 2.2 | 2.4 | V | V _{IN} Decreasing |

AC Characteristics

| Deremeter | Symbol Limit | | | Linit | 0 4:4: | |
|----------------------|-------------------|-----|-----|-------|--------|------------------|
| Parameter | Symbol | Min | Тур | Max | Unit | Conditions |
| Output Rise Time | t _{ON1} | ı | 1 | 6 | ms | $R_L = 20\Omega$ |
| Output Turn ON Time | t _{ON2} | ı | 1.5 | 10 | ms | $R_L = 20\Omega$ |
| Output Fall Time | t _{OFF1} | ı | 1 | 20 | μs | $R_L = 20\Omega$ |
| Output Turn OFF Time | t _{OFF2} | ı | 3 | 40 | μs | $R_L = 20\Omega$ |
| /OC Delay Time | t _{/OC} | 10 | 15 | 20 | ms | |

Electrical Characteristics – continued

BD2221G (V_{IN} = 5V, Ta= 25°C, unless otherwise specified.)

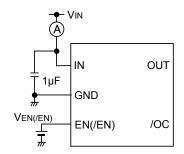
DC Characteristics

| Parameter | Symbol | | Limit | | Unit | Conditions |
|------------------------------|------------------|------|-------|------|-------|---|
| Parameter | Gyllibol | Min | Тур | Max | Offic | |
| Operating Current | I _{DD} | ı | 110 | 160 | μA | $V_{/EN} = 0V$ $V_{OUT} = Open$ |
| Standby Current | I _{STB} | - | 0.01 | 5 | μΑ | $V_{/EN} = 5V$ $V_{OUT} = Open$ |
| /EN Input Voltage | $V_{/ENH}$ | 2.0 | - | - | V | High Input |
| /Liv input voltage | $V_{/ENL}$ | ı | - | 0.8 | V | Low Input |
| /EN Input Leakage | I _{/EN} | -1.0 | +0.01 | +1.0 | μΑ | V _{/EN} = 0V or 5V |
| ON-Resistance | Ron | 1 | 160 | 210 | mΩ | I _{OUT} = 50mA |
| Switch Leak Current | I _{LSW} | - | - | 1.0 | μΑ | V _{/EN} = 0V, V _{OUT} = 0V |
| Reverse Leak Current | I _{REV} | - | - | 1.0 | μA | V _{OUT} = 5.5V, V _{IN} = 0V |
| Over-Current Threshold | I _{TH} | 0.5 | - | 1.0 | Α | |
| Short Circuit Output Current | I _{SC} | 0.35 | - | - | Α | V _{OUT} = 0V, RMS |
| /OC Output Low Voltage | V _{/OC} | - | - | 0.4 | V | I _{/OC} = 0.5mA |
| UVLO Threshold | V_{TUVH} | 2.1 | 2.3 | 2.5 | V | V _{IN} Increasing |
| OVEO IIIIesiioid | V_{TUVL} | 2.0 | 2.2 | 2.4 | V | V _{IN} Decreasing |

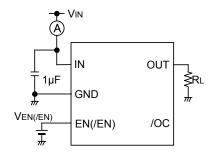
AC Characteristics

| Dorameter | Cymbol | Limit | | | l lmit | O and distinguish |
|----------------------|-------------------|-------|-----|-----|--------|-------------------|
| Parameter | Symbol | Min | Тур | Max | Unit | Conditions |
| Output Rise Time | t _{ON1} | - | 1 | 6 | ms | $R_L = 20\Omega$ |
| Output Turn ON Time | t _{ON2} | - | 1.5 | 10 | ms | $R_L = 20\Omega$ |
| Output Fall Time | t _{OFF1} | - | 1 | 20 | μs | $R_L = 20\Omega$ |
| Output Turn OFF Time | t _{OFF2} | - | 3 | 40 | μs | $R_L = 20\Omega$ |
| /OC Delay Time | t _{/OC} | 10 | 15 | 20 | ms | |

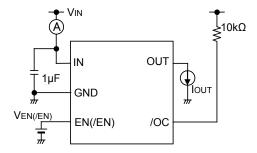
Measurement Circuit



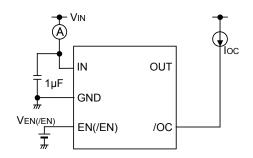
A. Operating Current



B. EN,/EN Input Voltage, Output Rise / Fall Time



C. ON-Resistance, Over-Current Detection



D. /OC Output Low Voltage

Figure 1. Measurement Circuit



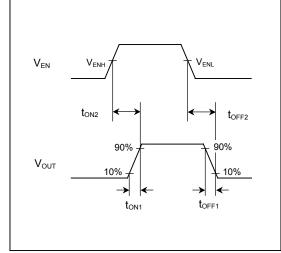


Figure 2. Output Rise / Fall Time (BD2220G)

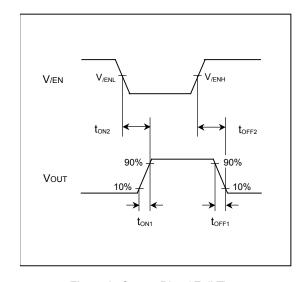


Figure 3. Output Rise / Fall Time (BD2221G)

Typical Performance Curves

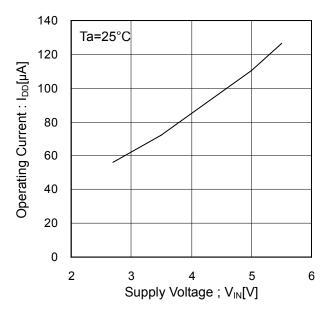


Figure 4. Operating Current vs Supply Voltage (EN, /EN Enable)

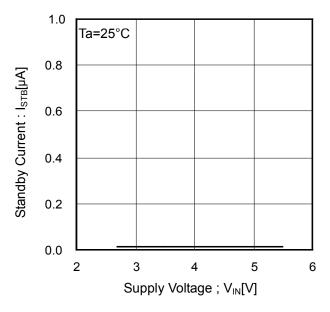


Figure 6. Standby Current vs Supply Voltage (EN, /EN Disable)

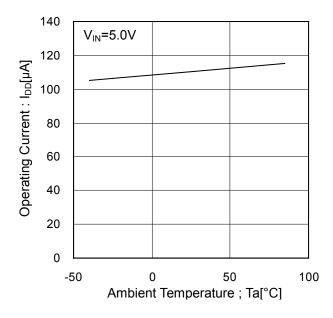


Figure 5. Operating Current vs Ambient Temperature (EN, /EN Enable)

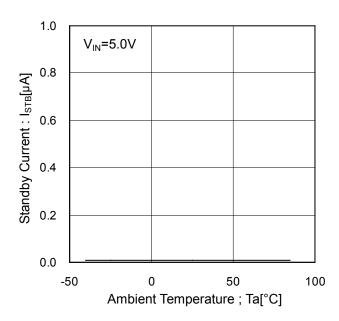


Figure 7. Standby Current vs Ambient Temperature (EN, /EN Disable)

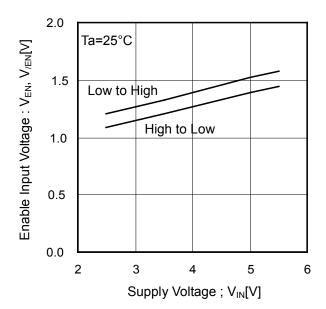


Figure 8. EN, /EN Input Voltage vs Supply Voltage

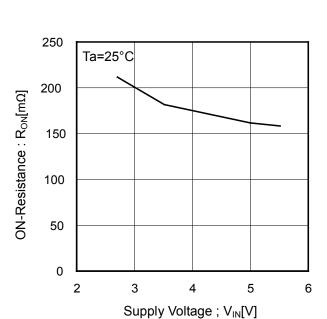


Figure 10. ON-Resistance vs Supply Voltage

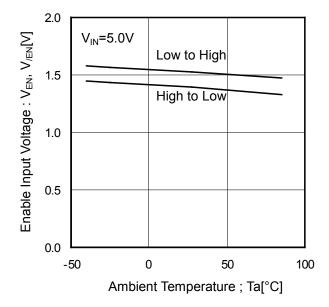


Figure 9. EN, /EN Input Voltage vs Ambient Temperature

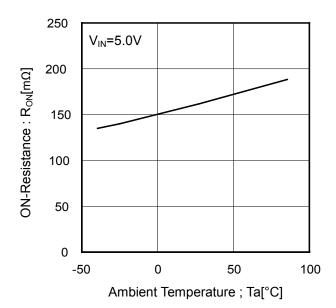


Figure 11. ON-Resistance vs Ambient Temperature

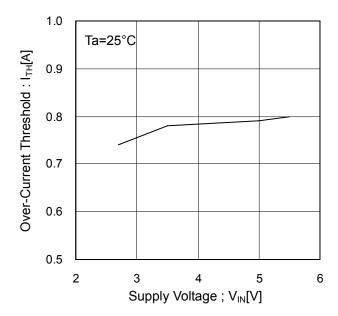


Figure 12. Over-Current Threshold vs Supply Voltage

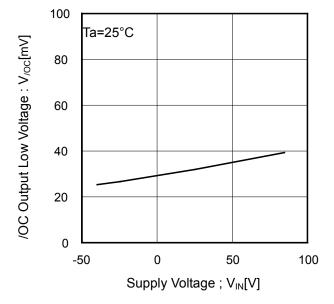


Figure 14. /OC Output Low Voltage vs Supply Voltage

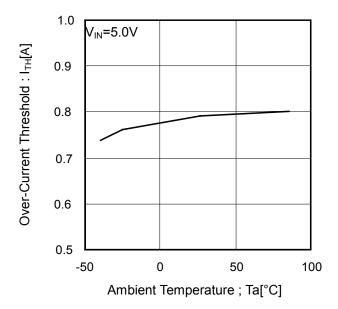


Figure 13. Over-Current Threshold vs Ambient Temperature

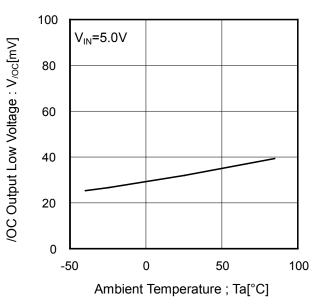


Figure 15. /OC Output Low Voltage vs Ambient Temperature

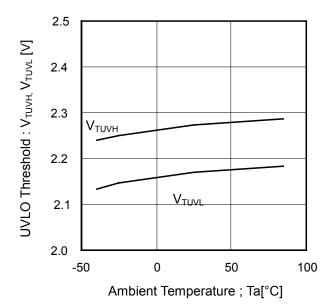


Figure 16. UVLO Threshold Voltage vs Ambient Temperature

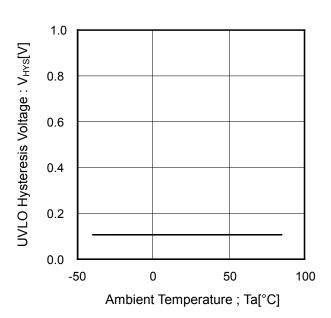


Figure 17. UVLO Hysteresis Voltage vs Ambient Temperature

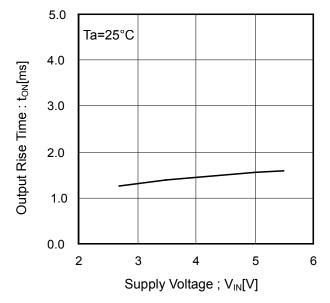


Figure 18. Output Rise Time vs Supply Voltage

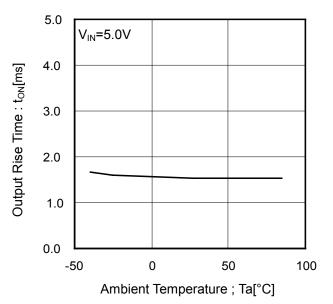


Figure 19. Output Rise Time vs Ambient Temperature

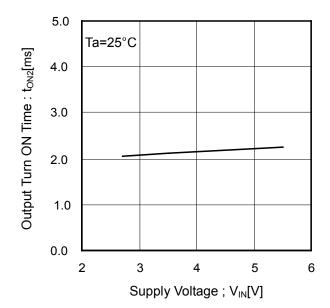


Figure 20. Output Turn ON Time vs Supply Voltage

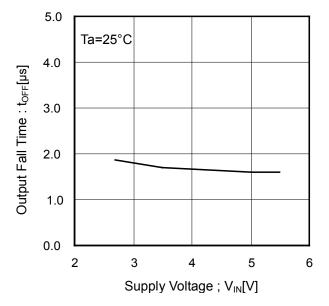


Figure 22. Output Fall Time vs Supply Voltage

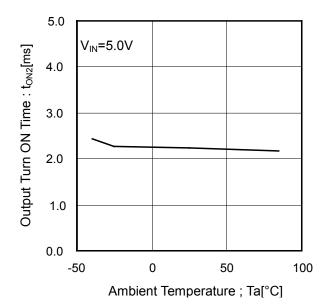


Figure 21. Output Turn ON Time vs Ambient Temperature

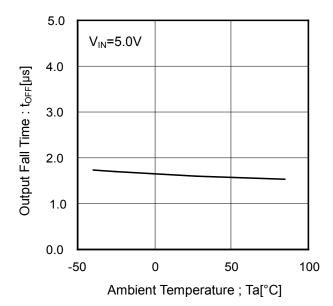


Figure 23. Output Fall Time vs Ambient Temperature

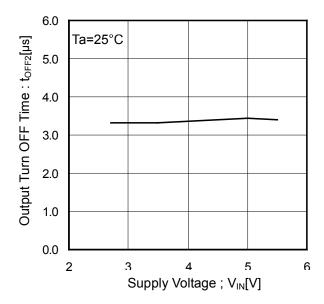


Figure 24. Output Turn OFF Time vs Supply Voltage

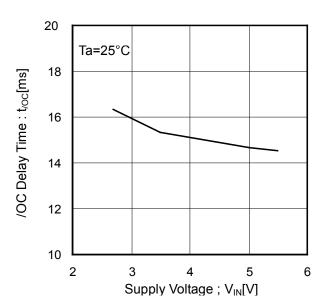


Figure 26. /OC Delay Time vs Supply Voltage

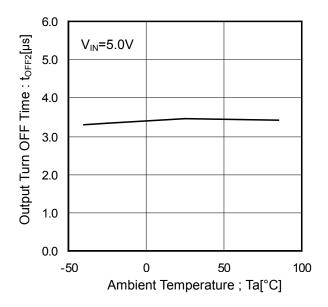


Figure 25. Output Turn OFF Time vs Ambient Temperature

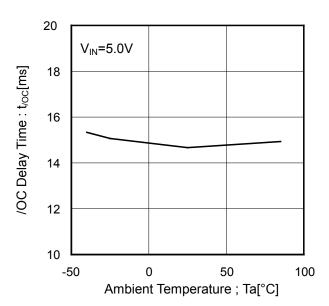


Figure 27. /OC Delay Time vs Ambient Temperature

Typical Waveforms

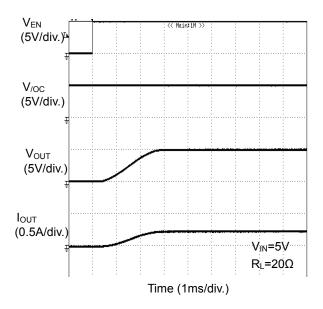


Figure 28. Output Rise Characteristic

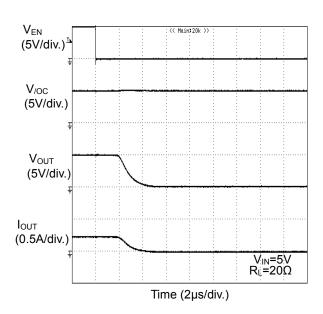


Figure 29. Output Fall Characteristic

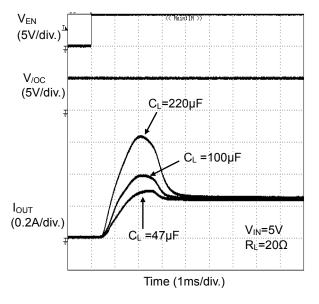


Figure 30. Inrush Current Response

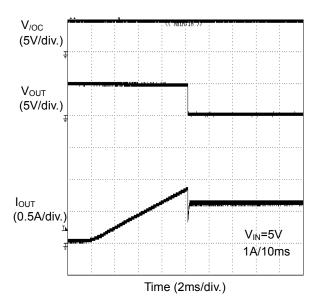


Figure 31. Over-Current Response Ramped Load

Typical Waveforms - continued

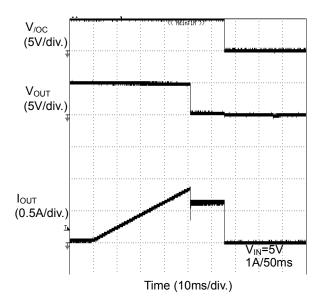


Figure 32. Over-Current Response Ramped Load

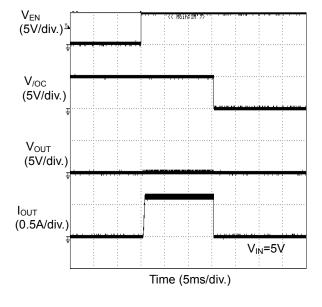


Figure 33. Over-Current Response Enable to Short-Circuit

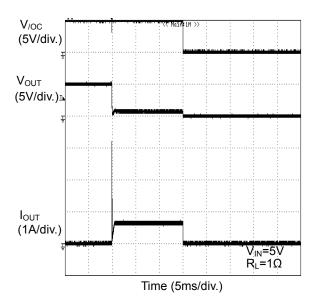


Figure 34. Over-Current Response 1Ω Load Connected at EN

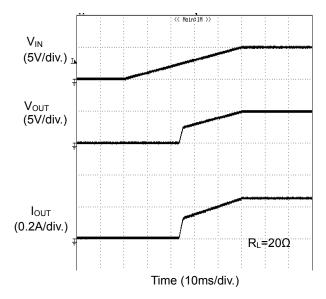


Figure 35. UVLO Response Increasing VIN

Typical Wave Forms - continued

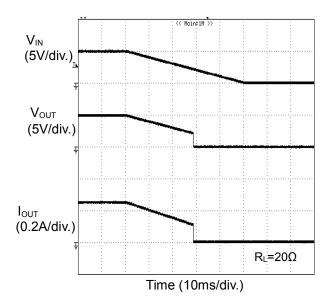
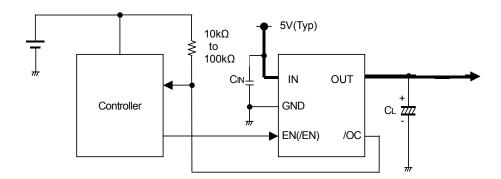


Figure 36. UVLO Response Decreasing V_{IN}

Typical Application Circuit



Application Information

When excessive current flows due to output short circuit or so, ringing occurs because of inductance between power source line and IC. This may cause bad effects on IC operations. In order to avoid this case, connect a bypass capacitor across IN terminal and GND terminal of IC. 1µF or higher is recommended.

Pull up /OC output by a resistance value of $10k\Omega$ to $100k\Omega$.

Set up value which satisfies the application of either C_L.

This application circuit does not guarantee its operation.

When using the circuit with changes to the external circuit constants, make sure to leave an adequate margin for external components including AC/DC characteristics as well as dispersion of the IC.

Functional Description

1. Switch Operation

IN terminal and OUT terminal are connected to the drain and the source of switch MOSFET respectively. The IN terminal is also used as power source input to internal control circuit.

When the switch is turned on from EN, /EN control input, the switch is bidirectional. IN terminal and OUT terminal are connected by a $160m\Omega$ (Typ) switch. Therefore, when the potential of OUT terminal is higher than that of IN terminal, current flows from OUT terminal to IN terminal. On the other hand, when the switch is turned OFF, it is possible to prevent current from flowing reversely from OUT to IN since a parasitic diode between the drain and the source of switch MOSFET is not present,

2. Thermal Shutdown Circuit (TSD)

If over-current would continue, the temperature of the IC would increase drastically. If the junction temperature were beyond 170°C (Typ) during the condition of over-current detection, thermal shutdown circuit operates and turns power switch off and outputs a fault flag (/OC). Then, when the junction temperature decreases lower than 150°C (Typ), power switch is turned on and fault flag (/OC) is cancelled. Unless the increase of the chip's temperature is removed or the output of power switch is turned off, this operation repeats.

Note: The thermal shutdown circuit operates when the switch is on (EN, /EN signal is active).

3. Over-Current Detection (OCD)

The over-current detection circuit limits current (I_{SC}) and outputs a fault flag (/OC) when current flowing in each MOSFET exceeds a specified value. There are three types of response against over-current. The over-current detection circuit works when the switch is on (EN, /EN signal is active).

- (1) When the switch is turned on while the output is in short circuit status.
 - When the switch is turned on while the output is in short circuit status, the switch goes into current limit status immediately.
- (2) When the output short circuits while the switch is on
 - When the output short circuits or high-current load is connected while the switch is on, very large current flows until the over-current limit circuit reacts. When the current detection and limit circuit works, current limitation is carried out.
- (3) When the output current increases gradually
 - When the output current increases gradually, current limitation does not work until the output current exceeds the over-current detection value. When it exceeds the detection value, current limitation is carried out.

4. Under Voltage Lockout (UVLO)

UVLO circuit prevents the switch from turning on until the V_{IN} exceeds 2.3V(Typ). If V_{IN} drops below 2.2V(Typ) while the switch is still ON, then UVLO will shut off the power switch. UVLO has a hysteresis of 100mV(Typ).

Note: Under voltage lockout circuit works when the switch is on (EN, /EN signal is active).

5. Fault Flag (/OC) Output

Fault flag output is an NMOS open drain output. At detection of over-current and/or thermal shutdown, the output level is low. Over-current detection has delay filter. This delay filter prevents current detection flags from being sent during instantaneous events such as inrush current at switch on or during hot plug. If fault flag output is unused, /OC pin should be connected to open or ground line.

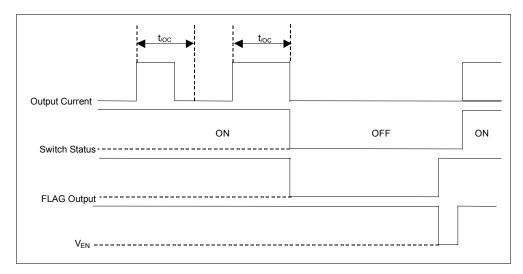


Figure 37. Over-Current Shutdown Operation (Reset at Toggle of EN (BD2220G)

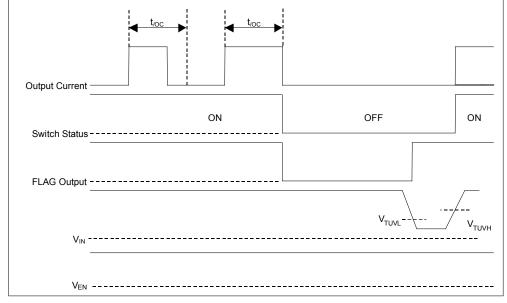
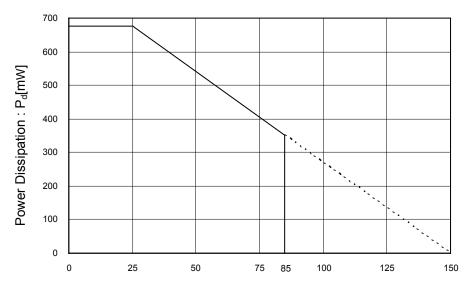


Figure 38. Over-Current Shutdown Operation (Reset at UVLO operation) (BD2220G)

Power Dissipation

(SSOP5 package)



Ambient Temperature ; Ta[°C]

70mm x 70mm x 1.6mm Glass Epoxy Board Figure 39. Power Dissipation Curve (Pd-Ta Curve)

I/O Equivalence Circuit

| Symbol | Pin No. | Equivalence circuit |
|-------------|---------|---------------------|
| EN (/EN) | 3 | EN (/EN) |
| OUT | 5 | OUT OUT |
| /OC | 4 | JOC JUNE 1000 |

Operational Notes

1. Reverse Connection of Power Supply

Connecting the power supply in reverse polarity can damage the IC. Take precautions against reverse polarity when connecting the power supply, such as mounting an external diode between the power supply and the IC's power supply pins.

2. Power Supply Lines

Design the PCB layout pattern to provide low impedance supply lines. Separate the ground and supply lines of the digital and analog blocks to prevent noise in the ground and supply lines of the digital block from affecting the analog block. Furthermore, connect a capacitor to ground at all power supply pins. Consider the effect of temperature and aging on the capacitance value when using electrolytic capacitors.

3. Ground Voltage

Ensure that no pins are at a voltage below that of the ground pin at any time, even during transient condition.

4. Ground Wiring Pattern

When using both small-signal and large-current ground traces, the two ground traces should be routed separately but connected to a single ground at the reference point of the application board to avoid fluctuations in the small-signal ground caused by large currents. Also ensure that the ground traces of external components do not cause variations on the ground voltage. The ground lines must be as short and thick as possible to reduce line impedance.

5. Thermal Consideration

Should by any chance the power dissipation rating be exceeded the rise in temperature of the chip may result in deterioration of the properties of the chip. The absolute maximum rating of the Pd stated in this specification is when the IC is mounted on a 70mm x 70mm x 1.6mm glass epoxy board. In case of exceeding this absolute maximum rating, increase the board size and copper area to prevent exceeding the Pd rating.

6. Recommended Operating Conditions

These conditions represent a range within which the expected characteristics of the IC can be approximately obtained. The electrical characteristics are guaranteed under the conditions of each parameter.

7. In rush Current

When power is first supplied to the IC, it is possible that the internal logic may be unstable and inrush current may flow instantaneously due to the internal powering sequence and delays, especially if the IC has more than one power supply. Therefore, give special consideration to power coupling capacitance, power wiring, width of ground wiring, and routing of connections.

8. Operation Under Strong Electromagnetic Field

Operating the IC in the presence of a strong electromagnetic field may cause the IC to malfunction.

9. Testing on Application Boards

When testing the IC on an application board, connecting a capacitor directly to a low-impedance output pin may subject the IC to stress. Always discharge capacitors completely after each process or step. The IC's power supply should always be turned off completely before connecting or removing it from the test setup during the inspection process. To prevent damage from static discharge, ground the IC during assembly and use similar precautions during transport and storage.

10. Inter-pin Short and Mounting Errors

Ensure that the direction and position are correct when mounting the IC on the PCB. Incorrect mounting may result in damaging the IC. Avoid nearby pins being shorted to each other especially to ground, power supply and output pin. Inter-pin shorts could be due to many reasons such as metal particles, water droplets (in very humid environment) and unintentional solder bridge deposited in between pins during assembly to name a few.

Operational Notes - continued

11. Unused Input Pins

Input pins of an IC are often connected to the gate of a MOS transistor. The gate has extremely high impedance and extremely low capacitance. If left unconnected, the electric field from the outside can easily charge it. The small charge acquired in this way is enough to produce a significant effect on the conduction through the transistor and cause unexpected operation of the IC. So unless otherwise specified, unused input pins should be connected to the power supply or ground line.

12. Regarding the Input Pin of the IC

This monolithic IC contains P+ isolation and P substrate layers between adjacent elements in order to keep them isolated. P-N junctions are formed at the intersection of the P layers with the N layers of other elements, creating a parasitic diode or transistor. For example (refer to figure below):

When GND > Pin A and GND > Pin B, the P-N junction operates as a parasitic diode. When GND > Pin B, the P-N junction operates as a parasitic transistor.

Parasitic diodes inevitably occur in the structure of the IC. The operation of parasitic diodes can result in mutual interference among circuits, operational faults, or physical damage. Therefore, conditions that cause these diodes to operate, such as applying a voltage lower than the GND voltage to an input pin (and thus to the P substrate) should be avoided.

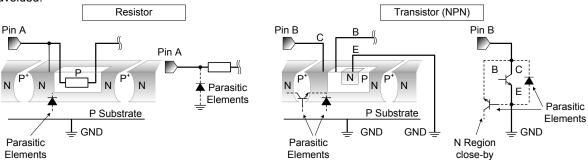


Figure 40. Example of monolithic IC structure

13. Ceramic Capacitor

When using a ceramic capacitor, determine the dielectric constant considering the change of capacitance with temperature and the decrease in nominal capacitance due to DC bias and others.

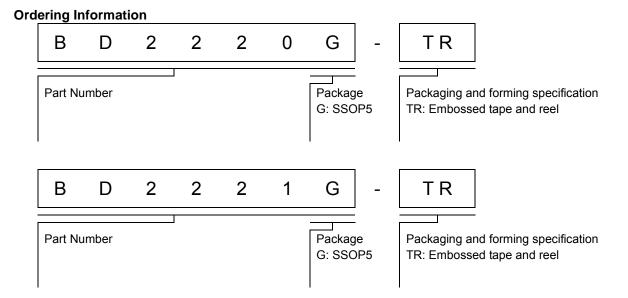
14. Thermal Shutdown Circuit(TSD)

This IC has a built-in thermal shutdown circuit that prevents heat damage to the IC. Normal operation should always be within the IC's power dissipation rating. If however the rating is exceeded for a continued period, the junction temperature (Tj) will rise which will activate the TSD circuit that will turn OFF all output pins. When the Tj falls below the TSD threshold, the circuits are automatically restored to normal operation.

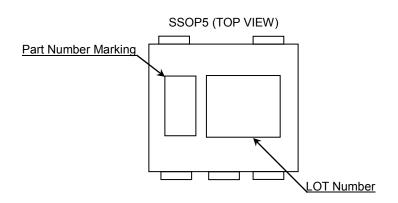
Note that the TSD circuit operates in a situation that exceeds the absolute maximum ratings and therefore, under no circumstances, should the TSD circuit be used in a set design or for any purpose other than protecting the IC from heat damage.

15. Thermal design

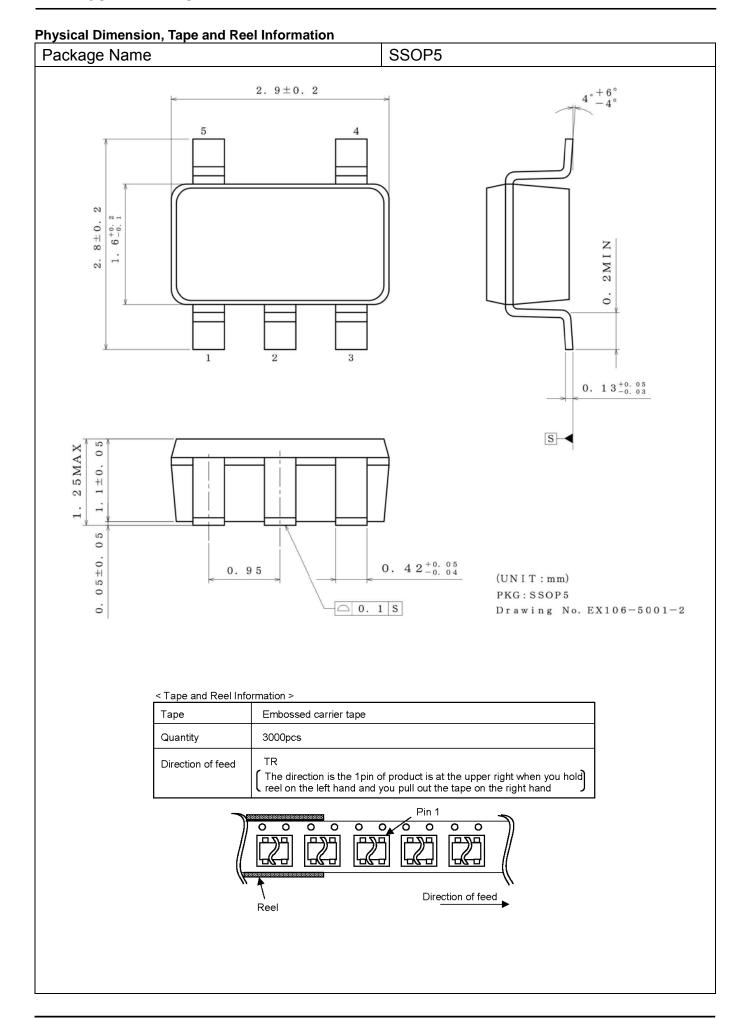
Perform thermal design in which there are adequate margins by taking into account the power dissipation (Pd) in actual states of use.



Marking Diagram



| Part Number | Part Number Marking |
|-------------|---------------------|
| BD2220G | DX |
| BD2221G | DY |



Revision History

| Date | Revision | Changes |
|-------------|----------|--|
| 11.Mar.2013 | 001 | New Release |
| 25.Jun.2013 | 002 | Modified Y-axis of figure 4. Changed character color from RED to BLOCK of figure 16. |
| 21.Aug.2014 | 003 | Applied the ROHM Standard Style and improved understandability. |

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(Note1) Medical Equipment Classification of the Specific Applications

| JAPAN | USA | EU | CHINA | |
|---------|----------|----------|----------|--|
| CLASSⅢ | CL ACCTI | CLASSIIb | CLASSIII | |
| CLASSIV | CLASSⅢ | CLASSⅢ | CLASSIII | |

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 - [d] Use of our Products in places where the Products are exposed to static electricity or electromagnetic waves
 - [e] Use of our Products in proximity to heat-producing components, plastic cords, or other flammable items
 - [f] Sealing or coating our Products with resin or other coating materials
 - [g] Use of our Products without cleaning residue of flux (even if you use no-clean type fluxes, cleaning residue of flux is recommended); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
 - [h] Use of the Products in places subject to dew condensation
- 4. The Products are not subject to radiation-proof design.
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- 8. Confirm that operation temperature is within the specified range described in the product specification.
- 9. ROHM shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document.

Precaution for Mounting / Circuit board design

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- 2. In principle, the reflow soldering method must be used; if flow soldering method is preferred, please consult with the ROHM representative in advance.

For details, please refer to ROHM Mounting specification

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This Product is electrostatic sensitive product, which may be damaged due to electrostatic discharge. Please take proper caution in your manufacturing process and storage so that voltage exceeding the Products maximum rating will not be applied to Products. Please take special care under dry condition (e.g. Grounding of human body / equipment / solder iron, isolation from charged objects, setting of lonizer, friction prevention and temperature / humidity control).

Precaution for Storage / Transportation

- 1. Product performance and soldered connections may deteriorate if the Products are stored in the places where:
 - [a] the Products are exposed to sea winds or corrosive gases, including Cl2, H2S, NH3, SO2, and NO2
 - [b] the temperature or humidity exceeds those recommended by ROHM
 - [c] the Products are exposed to direct sunshine or condensation
 - [d] the Products are exposed to high Electrostatic
- 2. Even under ROHM recommended storage condition, solderability of products out of recommended storage time period may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is exceeding the recommended storage time period.
- 3. Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.
- 4. Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

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